

Silicon NPN Power Transistors

2SC3830

DESCRIPTION

- With TO-220C package
- High voltage
- High speed switching

APPLICATIONS

- For switching regulator and general purpose applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter

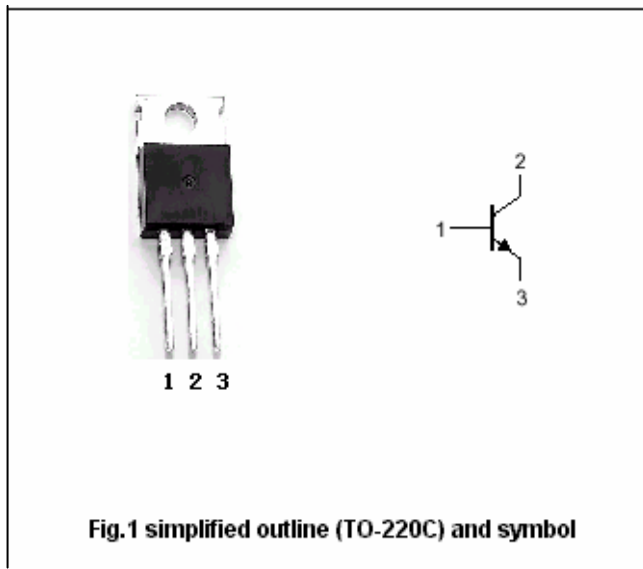


Fig.1 simplified outline (TO-220C) and symbol

Absolute maximum ratings(Ta=25°C)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V _{CBO}	Collector-base voltage	Open emitter	600	V
V _{CEO}	Collector-emitter voltage	Open base	500	V
V _{EBO}	Emitter-base voltage	Open collector	10	V
I _C	Collector current		6	A
I _{CM}	Collector current-peak		12	A
I _B	Base current		2	A
P _C	Collector dissipation	T _C =25°C	50	W
T _j	Junction temperature		150	°C
T _{stg}	Storage temperature		-55~150	°C

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CHARACTERISTICS

Tj=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	$I_C=25mA ; I_B=0$	500			V
V_{CEsat}	Collector-emitter saturation voltage	$I_C=2A ; I_B=0.4A$			0.5	V
V_{BEsat}	Base-emitter saturation voltage	$I_C=2A ; I_B=0.4A$			1.3	V
I_{CBO}	Collector cut-off current	$V_{CB}=600V ; I_E=0$			1	mA
I_{EBO}	Emitter cut-off current	$V_{EB}=10V ; I_C=0$			100	μA
h_{FE}	DC current gain	$I_C=2A ; V_{CE}=4V$	10		30	
f_T	Transition frequency	$I_C=0.5A ; V_{CE}=12V$		8		MHz
C_{OB}	Output capacitance	$f=1MHz ; V_{CB}=10V$		45		pF

Switching times

t_{on}	Turn-on time	$V_{CC}=200V ; I_C=2A$ $I_{B1}=0.2A ; I_{B2}=-0.4A ;$ $R_L=100\Omega$			1.0	μs
t_{stg}	Storage time				4.5	μs
t_f	Fall time				0.5	μs

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PACKAGE OUTLINE

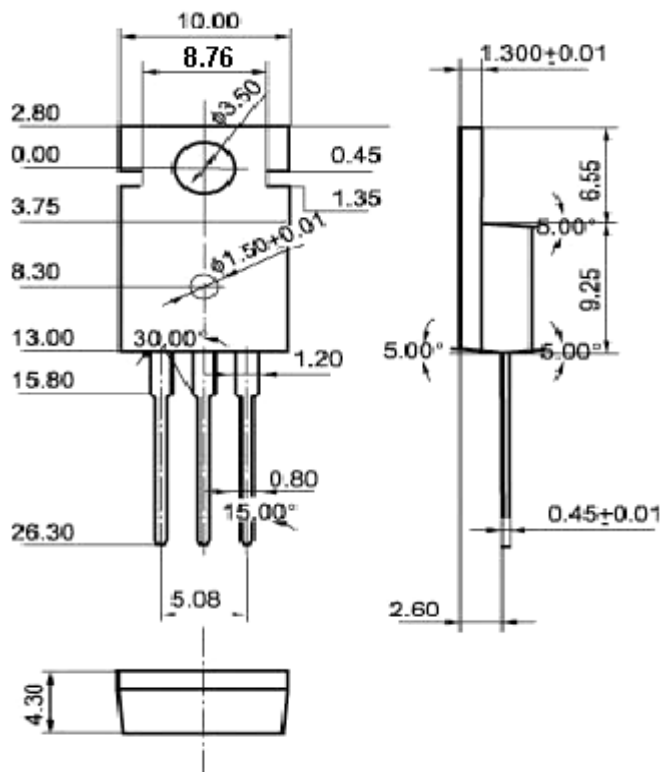


Fig.2 Outline dimensions (unindicated tolerance:±0.10 mm)

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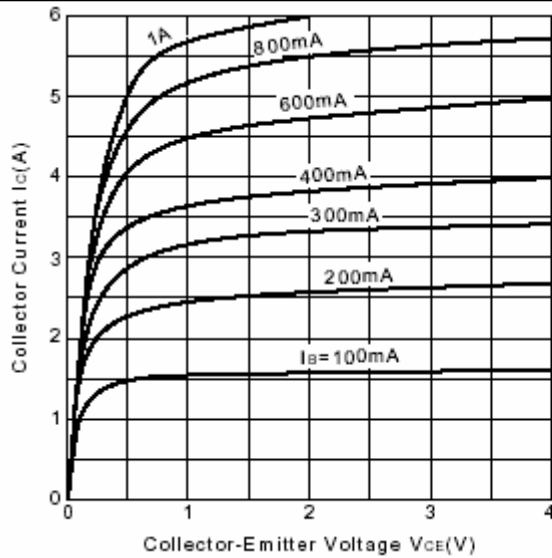


Fig.3 Static Characteristic

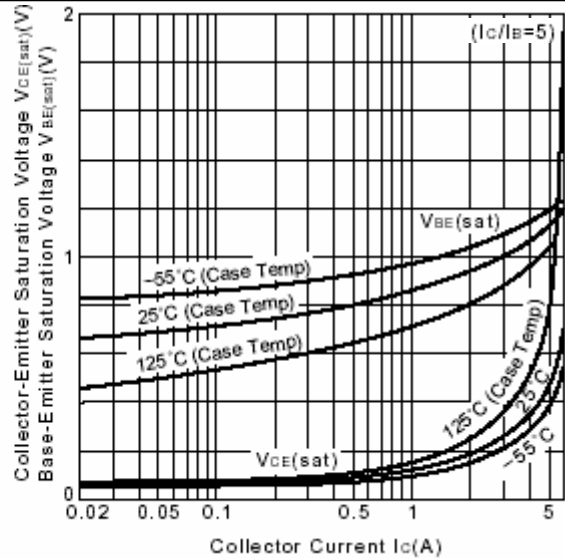


Fig.4 Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

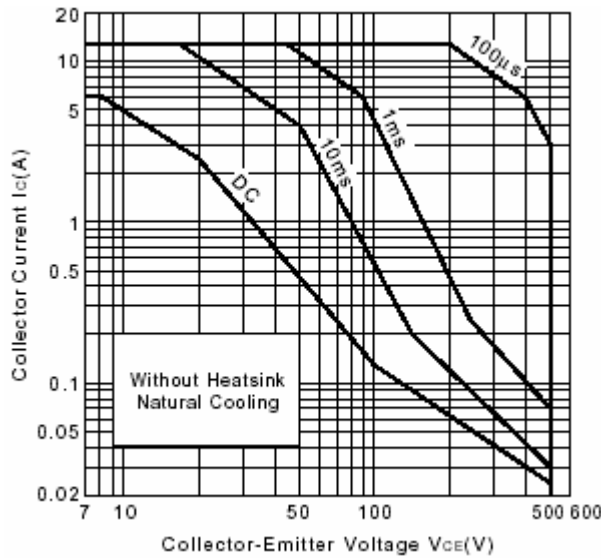


Fig.5 Safe Operating Area

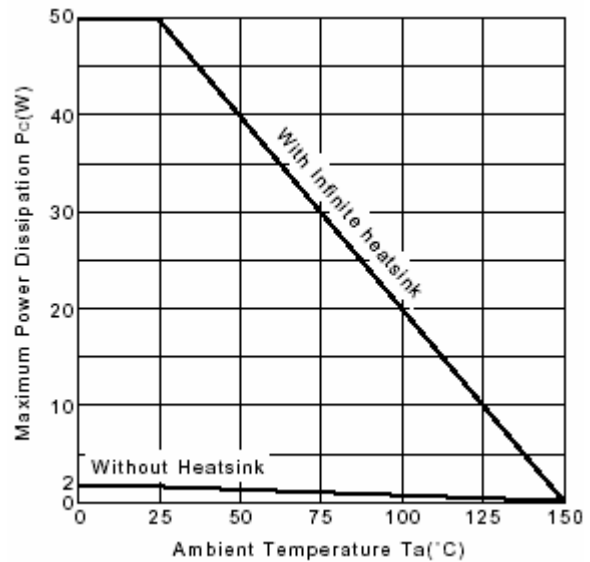


Fig.6 Power Derating

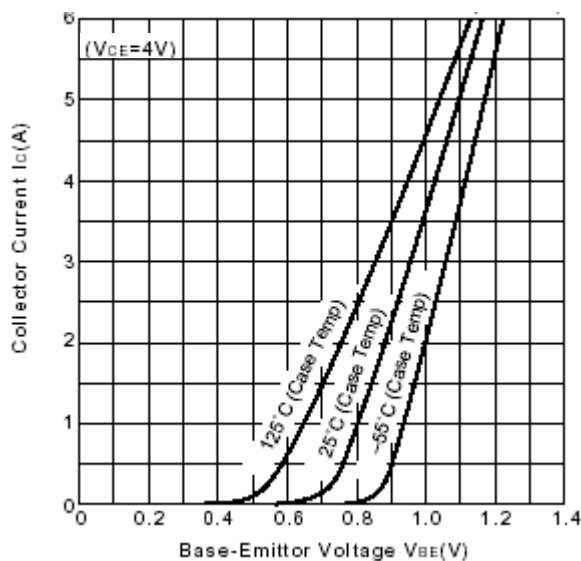


Fig.7 I_c-V_{BE}

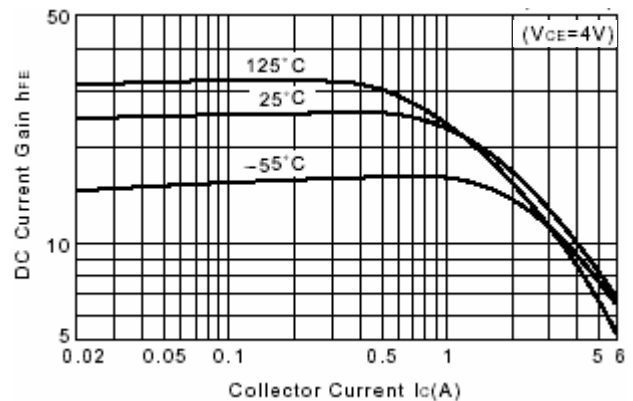


Fig.8 DC current Gain